Zener Diode

DD3X062J0L

Panasonic

DD3X062J0L

Silicon epitaxial planar type

For surge absorption circuit

■ Features

- Low terminal capacitance Ct
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol 51
- Basic Part Number :
 Dual DD2S062 (Common anode)

■ Packaging

Embossed type (Thermo-compression sealing) 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

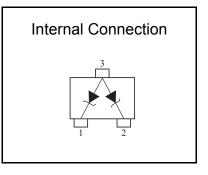
Parameter	Symbol	Rating	Unit
Repetitive peak forward current	IFRM	200	mA
Total power dissipation *1	PT	200	mW
Electrostatic discharge *2	ESD	±15	kV
Junction temperature	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C

Note) *1: PT = 200 mW achieved with a printed circuit board.

(2 Diode total)

*2: Test method:IEC61000_4_2(C = 150 pF,R = 330 Ω , Contact discharge:10 times)

Unit: mm 2. 9 0. 4 0. 16 (0. 95) (0. 95) 1. 9 1. Cathode1 2. Cathode2 3. Anode1,2 Panasonic Mini3-G3-B JEITA SC-59A Code TO-236AA/SOT-23



■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 5 mA	5.90		6.50	V
Zener operating resistance	RZ	IZ = 5 mA			30	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			100	Ω
Reverse current	IR	VR = 5.5 V			3	μA
Temperature coefficient of zener voltage *3	SZ	IZ = 5 mA		2.5		mV/°C
Terminal Capacitance	Ct	VR = 0 V, f = 1 MHz		10		pF

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.
 - *1: The temperature must be controlled 25°C for VZ mesurement.
 VZ value measured at other temperature must be adjusted to VZ (25°C)
 - *2: VZ guaranted 20 ms after current flow.
 - *3: Tj = 25° C to 150° C

Established: 2012-02-16

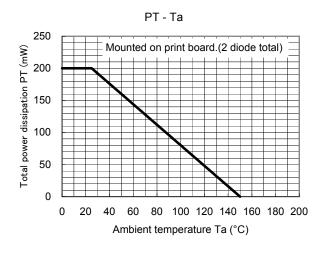
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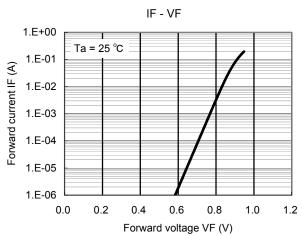
Revised

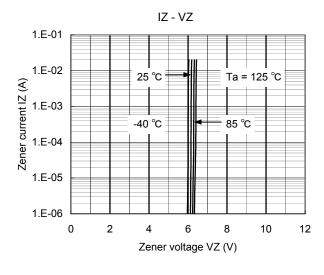
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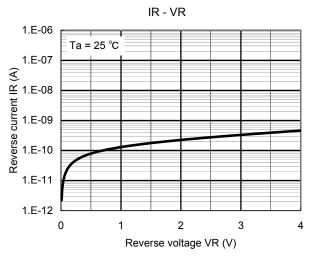
Zener Diode DD3X062J0L

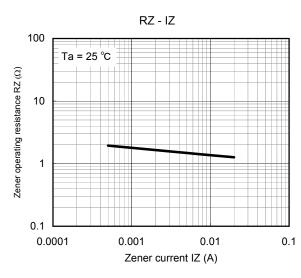
Technical Data (reference)

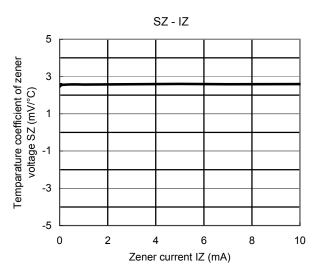












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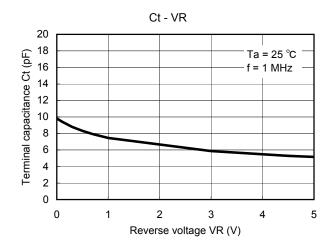
Established: 2012-02-16 Revised: 2013-11-01

Panasonic

Zener Diode

DD3X062J0L

Technical Data (reference)



Established: 2012-02-16 Revised: 2013-11-01

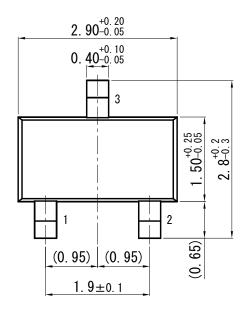
Zener Diode

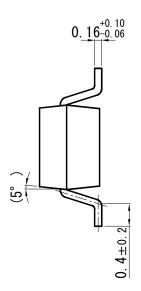
DD3X062J0L

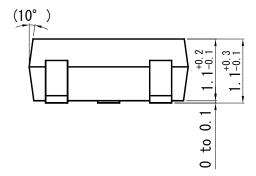
Mini3-G3-B

Panasonic

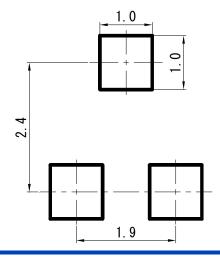
Unit: mm







■ Land Pattern (Reference) (Unit: mm)



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Established: 2012-02-16 Revised: 2013-11-01

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